OPI150, OPI153, OPI155

Features:

- 50 kV electrical isolation
- Choice of phototransistor or photodarlington output
- High speed 5 Mbit/sec (NRZ) OPI155 only
- Hermetically sealed LED and photosensor
- Base contact lead for conventional transistor biasing
- TX and TXV process available (see Hi-Rel section)

Description:

Each **OPI150** and **OPI153** is an optically coupled isolator that contains an infrared emitting diode and a NPN silicon phototransistor (OPI150) or photodarlington (OPI153), each sealed in an individual hermetically sealed package. The diode and phototransistor or diode and photodarlington are then optically coupled by means of a light pipe and mounted in a high dielectric plastic housing. These devices are designed for applications that require very high isolation between input and output.

The **OPI155** is a high-speed optical coupled isolator that contains a high speed monolithic photo-IC comprised of a photodiode and a DC amplifier that drives an open collector output Schottky transistor. It is optically coupled by means of an internal light pipe. The LED and sensor are both in separate hermetically sealed packages that are then mounted in a high dielectric plastic housing. This device is designed for applications that require high speed *and* high voltage isolation between the input and output.

Ordering Information

CTR

Min / Max

10/NA

25 / NA

80 / NA

Isolation

Voltage

(,000)

50

Sensor

Transistor

Darlington

TIA –OC

TX and TXV devices are available. Please contact your local representative or OPTEK for more information.

Part

Number

OPI150

OPI153

OPI155

LED

Peak

Wavelength

890 nm

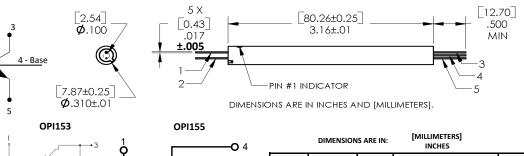
890 nm or 935

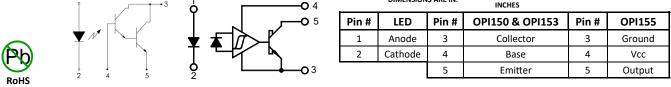
nm

850 nm

Applications:

- Requiring high voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment
 OPI150





General Note

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 V_{CE}

(Volts)

Max

30

15

18

I_F (mA)

Typ / Max

16/50

30 / 50

10/50

Lead

Length /

Spacing

0.40" /

3.16"

2.54

Ø.100



OPI150, OPI153, OPI155

Electrical Specifications

Absolute Maximum Ratings ($T_A = 25^{\circ}$ C unless otherwise noted)	
Operating Temperature Range	-40° C to +85° C
Storage Temperature Range	-40° C to +85° C
Input-to-Output Isolation Voltage ⁽¹⁾⁽²⁾	±50 kVDC
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 seconds with soldering iron] ⁽³⁾	260° C
Input Diode	
Continuous Forward Current	50 mA
Reverse Voltage	3 V
Power Dissipation ⁽⁴⁾	200 mW
Output Phototransistor or Photodarlington (OPI150, OPI153)	
Collector-Base Voltage OPI150 OPI153	30 V 20 V
Collector-Emitter Voltage OPI150 OPI153	30 V 15 V
Emitter-Collector Voltage	5.0 V
Power Dissipation ⁽⁵⁾	250 mW
Output Photosensor (OPI155)	
Supply Voltage	-0.5 to 7 V
Output Voltage	-0.5 to 18 V
Output Current	25 mA
Open-Collector Power Dissipation	40 mW
Power Dissipation ⁽⁵⁾	250 mW

Notes:

(1) For OPI150 and OPI153, measured with input leads and output leads shorted.

(2) For OPI155, measured with input and output leads shorted and relative humidity of less than 50%.

(3) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

(4) Derate linearly 3.33 mW/° C above 25° C.

(5) Derate linearly 4.17 mW/° C above 25° C.

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OPI150, OPI153, OPI155

Electrical Specifications

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS
	(For OPI150 & OPI153, see OP236 for addition - for reference only.)	nal inforn	nation -	for refer	ence only.	For OPI155, see OP235W for additional
V _F	Forward Voltage OPI150, OPI153 OPI155		1.3 1.2	1.6 1.6	V	I _F = 50 mA I _F = 10 mA
I _R	Reverse Current	-	0.1	100	μΑ	V _R = 3 V
	totransistor or Photodarlington (For OPI150, se - for reference only.)	e OP8055	SL for ad	ditional i	nformatio	n, for OPI153, see OP830SL for additiona
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage OPI150 OPI153	30 15	-	-	V	I _c = 1 mA
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage OPI150, OPI153	5	-	-	V	I _F = 100 μA
V _{(BR)CBO}	Collector-Base Breakdown Voltage OPI150 OPI153	30 20	-	-	V	I _c = 100 μA
I _{CEO}	Collector-Emitter Dark Current OPI150 OPI153		-	100 500	nA	V _{CE} = 10 V
I _{CBO}	Collector-Base Dark Current OPI150	-	-	-	nA	V _{CB} = 10 V
Coupled (OF	PI150, OPI153)					
I _{C/} I _F	DC Current Transfer Ratio OPI150 OPI153	10 25	-	-	%	I _F = 10 mA, V _{CE} = 5 V I _F = 20 mA, V _{CE} = 5 V
I _{CB(ON)}	Ib0State Photodiode Current OPI150	10	-	-	μΑ	I _F = 20 mA, V _{CB} = 5 V
V _{CE(SAT)}	Saturation Voltage OPI150 OPI153	-	-	0.5 1.2	v	I _F = 16 mA, I _C = 1 mA I _F = 30 mA, I _C = 2 mA

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OPI150, OPI153, OPI155

Electrical Specifications

Electrical Characteristics (T _A = 25° C unless otherwise noted)								
SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS		
Output Pho	otosensor (OPI155)							
I _{ОН}	High Level Output Current OPI155	-	-	250	μΑ	$V_0 = 18 V$, $I_F = 0$, $V_{CC} = Open$		
І _{ссн}	High Level Supply Current OPI155	-	-	6.5	mA	V _{cc} = 5.25 V, I _F = 0, V _o = Open		
I _{CCL}	Low Level Supply Current OPI155	-	-	10	mA	V _{CC} = 5.25 V, I _F = 10 mA, V _O = 0		
V _{OL}	Low Level Output Voltage OPI155	-	-	0.5	V	V _{cc} = 5.25 V, I _F = 10 mA, I _o = 8 mA		
Switching (Characteristics (OPI155)	÷		<u>.</u>		·		
T _{phl}	Propagation Delay, High to Low	-	120	150	ns	V_{cc} = 5 V, I _F = 10 mA, R _L = 360 Ω		
T _{PLH}	Propagation Delay, Low to High	-	70	100				

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